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Substitute for Form 1449/PTO		<i>Complete if Known</i>	
<b>INFORMATION DISCLOSURE STATEMENT BY APPLICANT</b> (Use as many sheets as necessary)		Application Number	10/566,521
		Filing Date	September 25, 2006
		First Named Inventor	Volker HÄRLE
		Art Unit	1792
		Examiner Name	SONG, Matthew J.
Sheet	1	of	2
		Attorney Docket Number	
		5367-219PUS	

FOREIGN PATENT DOCUMENTS						
Examiner Initials*	Cite No. <sup>1</sup>	Foreign Patent Document	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	T <sup>6</sup>
		Country Code <sup>3</sup> , Number <sup>4</sup> Kind-Code <sup>5</sup> (if known)				
	BA	EP 0 472 221 A2	02/26/1992	NEC Corporation		✓
	BB	EP 1 005 067 A2	05/31/2000	Sony Corporation		✓
	BC	EP 0 388 733 A1	09/26/1990	Fujitsu Limited		✓
	BD	JP 05 226781 A	12/13/1993	Fujitsu Ltd.		Abstract

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NON PATENT LITERATURE DOCUMENTS			
Examiner Initials*	Cite No. <sup>1</sup>	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T <sup>2</sup>
	CA	Yang et al., "Selective area deposited blue GaN-InGaN multiple-quantum well light emitting diodes over silicon substrates", Applied Physics Letters, American Institute of Physics, Vol. 76, No. 3, pp. 273-275, January 17, 2000	
	CB	Miyata et al., "Selective growth of nanocrystalline Si dots using an ultrathin-Si-oxide/oxynitride mask", Applied Physics Letters, American Institute of Physics, New York, Vol. 77, No. 11, pp. 1620-1622, September 11, 2000	
	CC	P.R. Hageman et al., "Improvement of the Optical and Structural Properties of MOCVD Grown GaN on Sapphire by an in-situ SiN Treatment", Willey-VCH Verlag Berlin GmbH, phys. Stat. Sol. (a), Vol. 188, No. 2, pp. 659-662, (2001).	

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